

The documentation and process conversion measures necessary to comply with this revision shall be completed by 10 October 2000.

INCH-POUND

MIL-PRF-19500/231G  
AMENDMENT 1  
10 July 2000

## PERFORMANCE SPECIFICATION

SEMICONDUCTOR DEVICE, DIODE, SILICON, SWITCHING, TYPES 1N3600,  
1N4150-1, 1N4150UR-1, JAN, JANTX, AND JANTXV

This amendment forms a part of MIL-PRF-19500/231G, dated 28 March 1997, and is approved for use by all Departments and Agencies of the Department of Defense.

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Table II Groups A, B, C, and E electrical measurements, Step 3, Maximum Limits, Delete "50°C/W" and replace with "70°C/W".

## CONCLUDING MATERIAL

Custodians:  
Army - CR  
Navy - EC  
Air Force - 11  
DLA - CC

Preparing activity:  
DLA - CC

(Project 5961-2358)

Review activities:  
Army - AR, AV, MI, SM  
Navy - AS, CG, MC  
Air Force - 19, 99